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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



# BLC9G22XS-400AVT

Power LDMOS transistor

Rev. 2 — 2 December 2016

AMPLEON

Product data sheet

## 1. Product profile

### 1.1 General description

400 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 2110 MHz to 2200 MHz.

**Table 1. Typical performance**

*Typical RF performance at  $T_{case} = 25\text{ °C}$  in an asymmetrical Doherty production test circuit.*

*$V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 810\text{ mA}$  (main);  $V_{GS(amp)peak} = 0.7\text{ V}$ , unless otherwise specified.*

Test signal	f	$V_{DS}$	$P_{L(AV)}$	$G_p$	$\eta_D$	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
1-carrier W-CDMA	2110 to 2200	32	87	15.3	45	-34 <sup>[1]</sup>

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01 % probability on CCDF.

### 1.2 Features and benefits

- Excellent ruggedness
- High-efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 2110 MHz to 2200 MHz frequency range

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain2 (peak)		<p>aaa-014884</p>
2	drain1 (main)		
3	gate1 (main)		
4	gate2 (peak)		
5	source <a href="#">[1]</a>		
6	video decoupling (peak)		
7	video decoupling (main)		

[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLC9G22XS-400AVT	-	air cavity plastic earless flanged package; 6 leads	SOT1258-7

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		-6	+13	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		-6	+13	V
$T_{stg}$	storage temperature		-65	+150	°C
$T_j$	junction temperature		<a href="#">[1]</a>	225	°C
$T_{case}$	case temperature	operating	<a href="#">[1]</a>	+125	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$V_{DS} = 32\text{ V}; I_{Dq} = 800\text{ mA (main)};$ $V_{GS(amp)peak} = 0,4\text{ V}; T_{case} = 80\text{ °C}$		
		$P_L = 85\text{ W}$	0.25	k/W
		$P_L = 110\text{ W}$	0.26	k/W



## 6. Characteristics

**Table 6. DC characteristics**

$T_j = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Main device</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 1.62\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 162\text{ mA}$	1.5	2.0	2.5	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 28\text{ V}; I_D = 810\text{ mA}$	1.7	2.2	2.5	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 32\text{ V}$	-	-	2.8	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$	-	31	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	280	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 8.1\text{ A}$	-	11	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 5.67\text{ A}$	-	95	107	$\text{m}\Omega$
<b>Peak device</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 3.0\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 300\text{ mA}$	1.5	2.0	2.5	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 28\text{ V}; I_D = 1500\text{ mA}$	1.7	2.2	2.5	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 32\text{ V}$	-	-	2.8	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$	-	52	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	280	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 15\text{ A}$	-	20	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 10.5\text{ A}$	-	50	85	$\text{m}\Omega$

**Table 7. RF characteristics**

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH;  $f_1 = 2112.5$ ;  $f_2 = 2197.5\text{ MHz}$ ; RF performance at  $V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 810\text{ mA}$  (main);  $V_{GS(amp)peak} = 0.7\text{ V}$ ;  $T_{case} = 25\text{ °C}$ ; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 2110 MHz to 2200 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$G_p$	power gain	$P_{L(AV)} = 93\text{ W}$	14.3	15.3	-	dB
$RL_{in}$	input return loss	$P_{L(AV)} = 93\text{ W}$	-	-19	-12	dB
$\eta_D$	drain efficiency	$P_{L(AV)} = 93\text{ W}$	41	45	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 93\text{ W}$	-	-34	-29	dBc

**Table 8. RF characteristics**

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH;  $f = 2197.5\text{ MHz}$ ; RF performance at  $V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 810\text{ mA}$  (main);  $V_{GS(amp)peak} = 0.7\text{ V}$ ;  $T_{case} = 25\text{ °C}$ ; unless otherwise specified; in an asymmetrical Doherty production test circuit at a frequency of 2200 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$PAR_O$	output peak-to-average ratio	$P_{L(AV)} = 110\text{ W}$	6.7	7.2	-	dB
$P_{L(M)}$	peak output power	$P_{L(AV)} = 110\text{ W}$	504	580	-	W

## 7. Test information

### 7.1 Ruggedness in Doherty operation

The BLC9G22XS-400AVT is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 810\text{ mA}$ ;  $V_{GS(amp)peak} = 0.7\text{ V}$ ;  $f = 2112.5\text{ MHz}$ ;  $P_L = 126\text{ W}$  (5 dB OBO); 100 % clipping.

### 7.2 Impedance information

**Table 9. Typical impedance of main device**

Measured load-pull data of main device;  $I_{Dq} = 810\text{ mA}$  (main);  $V_{DS} = 32\text{ V}$ ; pulsed CW ( $t_p = 100\text{ }\mu\text{s}$ ;  $\delta = 10\text{ %}$ ).

f (MHz)	Z <sub>S</sub> [1] (Ω)	Z <sub>L</sub> [1] (Ω)	P <sub>L</sub> [2] (W)	η <sub>D</sub> [2] (%)	G <sub>p</sub> [2] (dB)
<b>Maximum power load</b>					
2110	2.0 – j6.0	1.3 – j3.2	270	56.6	17.6
2140	2.4 – j6.3	1.3 – j3.2	270	57.2	17.8
2200	2.9 – j6.5	1.3 – j3.2	267	56.9	17.9
<b>Maximum drain efficiency load</b>					
2110	2.0 – j6.0	2.5 – j2.2	210	68.4	20.1
2140	2.4 – j6.3	2.5 – j2.2	200	68.2	20.4
2200	2.9 – j6.5	2.5 – j2.2	200	67.7	20.5

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At 3 dB gain compression.

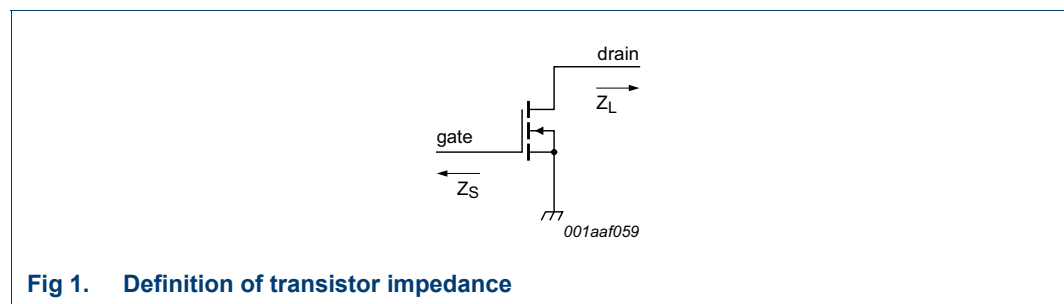
**Table 10. Typical impedance of peak device**

Measured load-pull data of peak device;  $I_{Dq} = 1500 \text{ mA (peak)}$ ;  $V_{DS} = 32 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L</sub> [2]	η <sub>D</sub> [2]	G <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
<b>Maximum power load</b>					
2110	2.0 – j6.0	2.5 – j3.8	430	56.5	17.7
2140	2.4 – j6.3	2.5 – j3.8	430	56.2	17.8
2200	2.9 – j6.5	2.5 – j3.8	425	55.2	17.8
<b>Maximum drain efficiency load</b>					
2110	2.0 – j6.0	3.4 – j2.9	390	62.5	18.9
2140	2.4 – j6.3	3.4 – j2.9	390	62.8	18.9
2200	2.9 – j6.5	3.4 – j2.1	360	62.9	19.5

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At 3 dB gain compression.



### 7.3 Recommended impedances for Doherty design

**Table 11. Typical impedance of main at 1 : 1 load**

Measured load-pull data of main device;  $I_{Dq} = 810 \text{ mA (main)}$ ;  $V_{DS} = 32 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L(3dB)</sub> [2]	η <sub>D</sub> [2]	G <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
2110	2.0 – j6.0	1.7 – j3.0	250	42	18.5
2140	2.4 – j6.3	1.7 – j2.8	250	43	18.8
2200	2.9 – j6.5	1.6 – j2.6	240	43	19.1

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At P<sub>L(AV)</sub> = 85 W.

**Table 12. Typical impedance of main device at 1 : 2.5 load**

Measured load-pull data of main device;  $I_{Dq} = 810 \text{ mA (main)}$ ;  $V_{DS} = 32 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L(3dB)</sub> [2]	η <sub>D</sub> [2]	G <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
2110	2.0 – j6.0	3.8 – j2.3	155	59	20.9
2140	2.4 – j6.3	3.8 – j1.9	145	60	21.2
2200	2.9 – j6.5	3.8 – j1.8	140	60	21.4

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At P<sub>L(AV)</sub> = 85 W.

**Table 13. Typical impedance of peak device at 1 : 1 load**

Measured load-pull data of peak device;  $I_{Dq} = 1500 \text{ mA (peak)}$ ;  $V_{DS} = 32 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L(3dB)</sub> [2]	η <sub>D</sub> [2]	G <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
2110	2.2 – j6.5	2.8 – j3.7	400	31.5	18.0
2140	2.7 – j6.9	2.8 – j3.5	400	31.5	18.2
2200	3.5 – j7.2	2.8 – j3.3	400	3.15	18.4

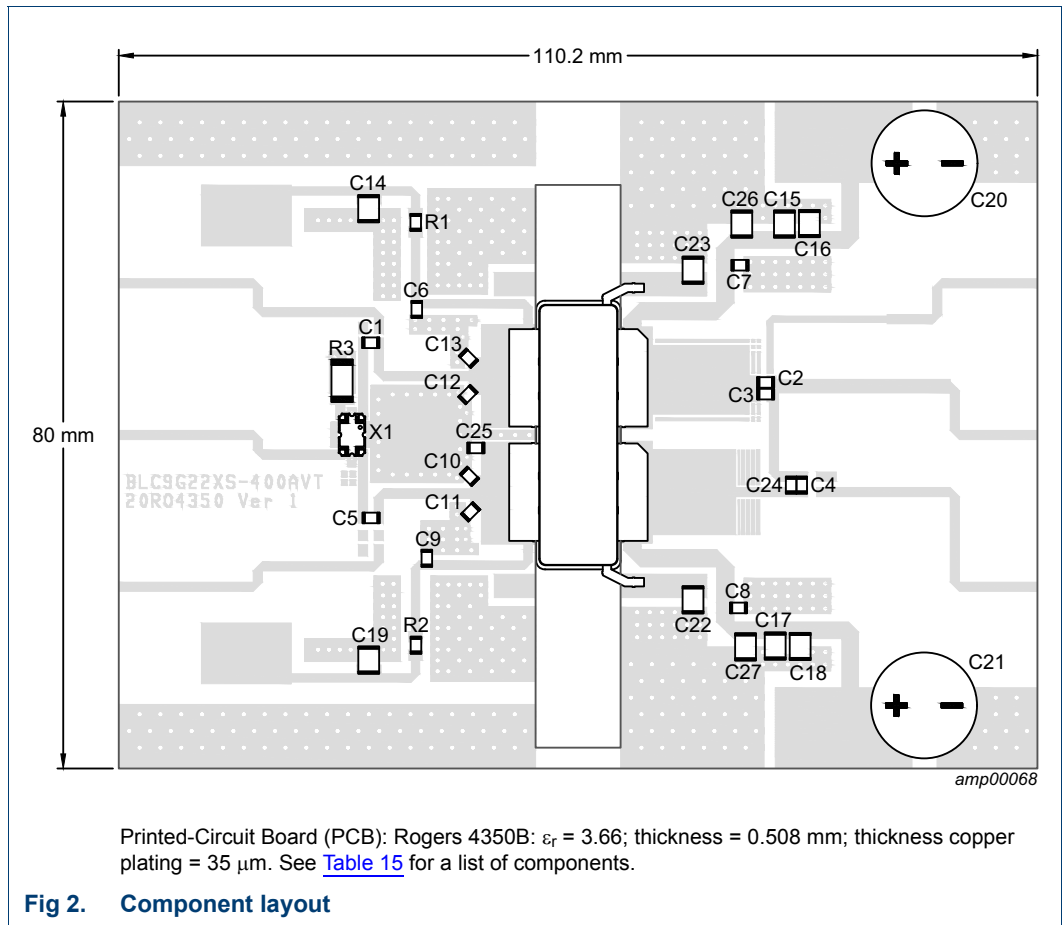
[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At P<sub>L(AV)</sub> = 85 W.

**Table 14. Off-state impedances of peak device**

f	Z <sub>off</sub>
(MHz)	(Ω)
2110	3.1 – j 3.9
2140	2.1 – j 2.6
2200	1.3 – j 0.7

7.4 Test circuit



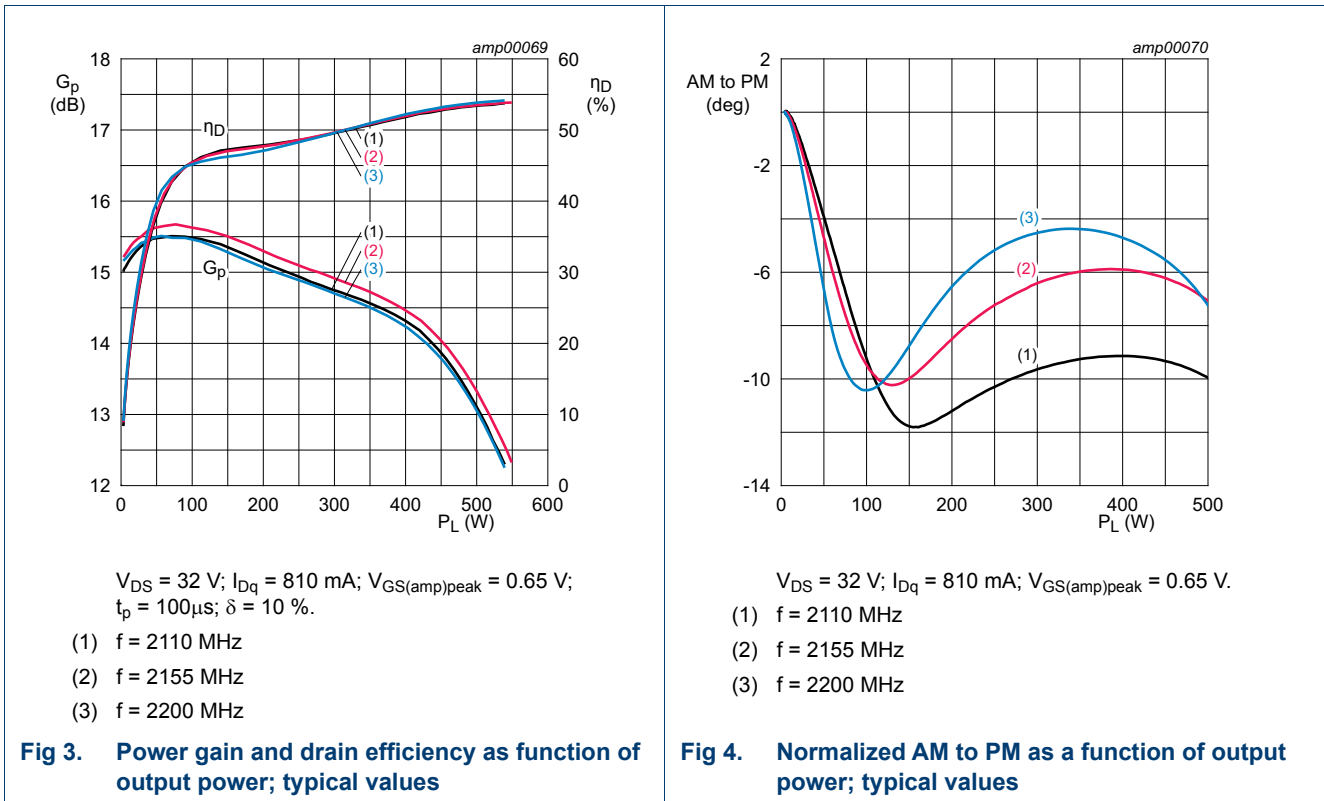
**Table 15. List of components**  
See Figure 2 for component layout.

Component	Description	Value	Remarks
C1, C2, C3, C4, C5, C6, C7, C8, C9, C24	multilayer ceramic chip capacitor	10 pF	Murata Hi-Q
C10, C11, C12	multilayer ceramic chip capacitor	1.2 pF	Murata Hi-Q
C13	multilayer ceramic chip capacitor	1.5 pF	Murata Hi-Q
C14, C15, C16, C17, C18, C19, C22, C23, C26, C27	multilayer ceramic chip capacitor	4.7 $\mu\text{F}$	Murata GRM32ER71H475KA88L
C20, C21	electrolytic capacitor	470 $\mu\text{F}$ , 63 V	
C25	multilayer ceramic chip capacitor	0.3 pF	ATC 100A
R1, R2	resistor	4.7 $\Omega$ , 1 %	SMD 0805
R3	resistor	50 $\Omega$ , 25 W	Anaren C16A50Z4
X1	hybrid coupler	2 dB	Anaren Xinger III, X3C20F1-02S



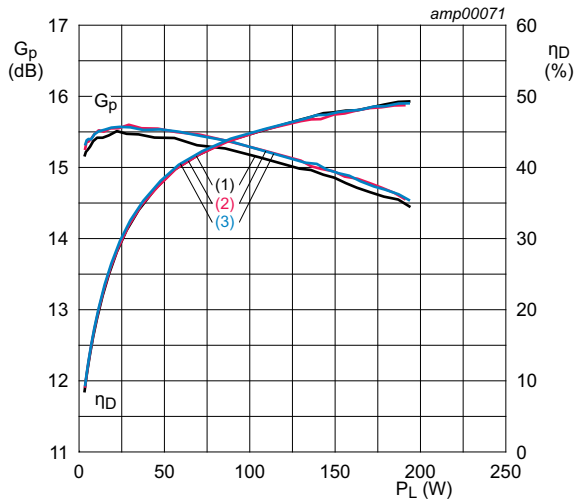
7.5 Graphical data

7.5.1 Pulsed CW



7.5.2 1-Carrier W-CDMA

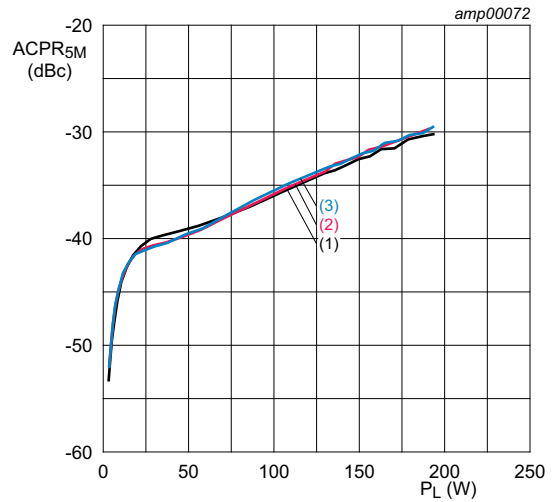
PAR = 9.6 dB per carrier at 0.01 % probability on the CCDF; 3GPP test model 1 with 64 DPCH (100 % clipping).



$V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 810\text{ mA}$ ;  $V_{GS(amp)peak} = 0.65\text{ V}$ .

- (1)  $f = 2112.5\text{ MHz}$
- (2)  $f = 2155\text{ MHz}$
- (3)  $f = 2167.5\text{ MHz}$

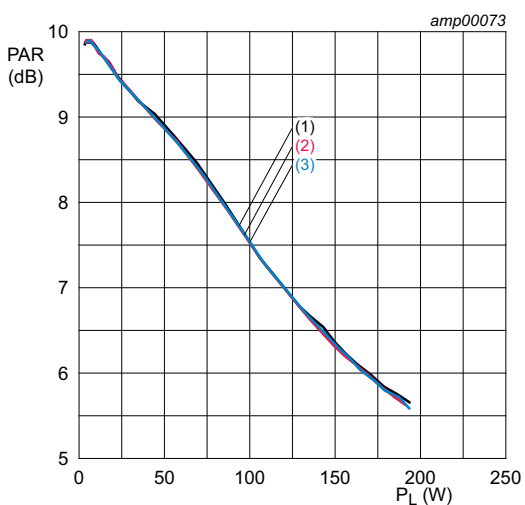
Fig 5. Power gain and drain efficiency as function of output power; typical values



$V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 810\text{ mA}$ ;  $V_{GS(amp)peak} = 0.65\text{ V}$ .

- (1)  $f = 2112.5\text{ MHz}$
- (2)  $f = 2155\text{ MHz}$
- (3)  $f = 2167.5\text{ MHz}$

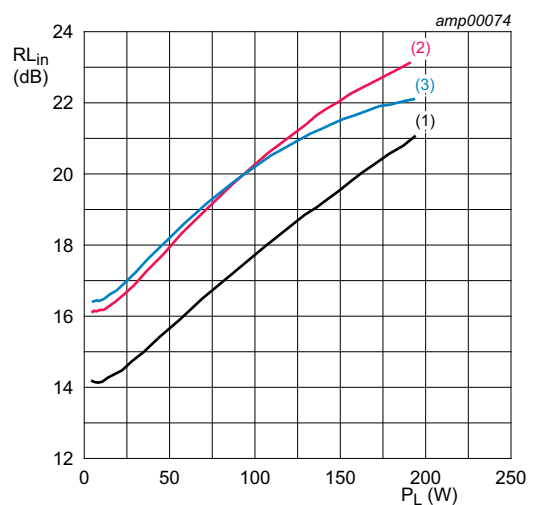
Fig 6. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



$V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 810\text{ mA}$ ;  $V_{GS(amp)peak} = 0.65\text{ V}$ .

- (1)  $f = 2112.5\text{ MHz}$
- (2)  $f = 2155\text{ MHz}$
- (3)  $f = 2167.5\text{ MHz}$

Fig 7. Peak-to-average power ratio as a function of output power; typical values



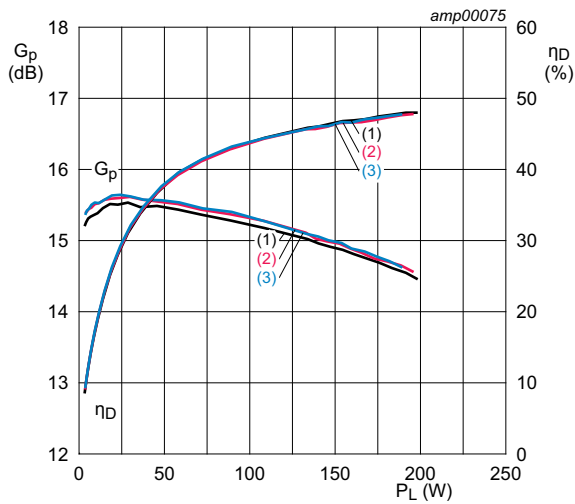
$V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 810\text{ mA}$ ;  $V_{GS(amp)peak} = 0.65\text{ V}$ .

- (1)  $f = 2112.5\text{ MHz}$
- (2)  $f = 2155\text{ MHz}$
- (3)  $f = 2167.5\text{ MHz}$

Fig 8. Input return loss as a function of output power; typical values

7.5.3 2-Carrier W-CDMA

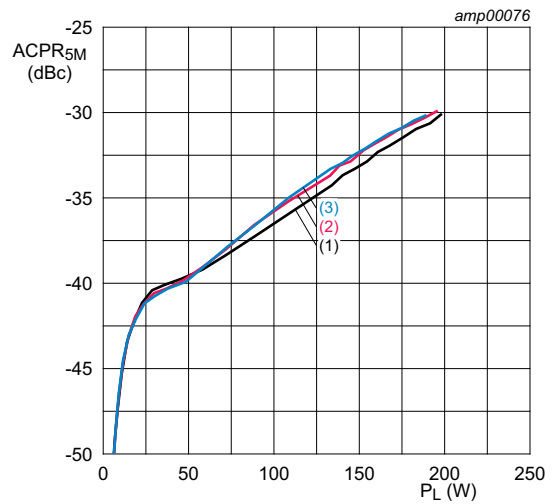
PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1 with 64 DPCH (46 % clipping).



$V_{DS} = 32\text{ V}; I_{Dq} = 810\text{ mA}; V_{GS(amp)peak} = 0.65\text{ V}.$

- (1)  $f = 2117.5\text{ MHz}$
- (2)  $f = 2155\text{ MHz}$
- (3)  $f = 2162.5\text{ MHz}$

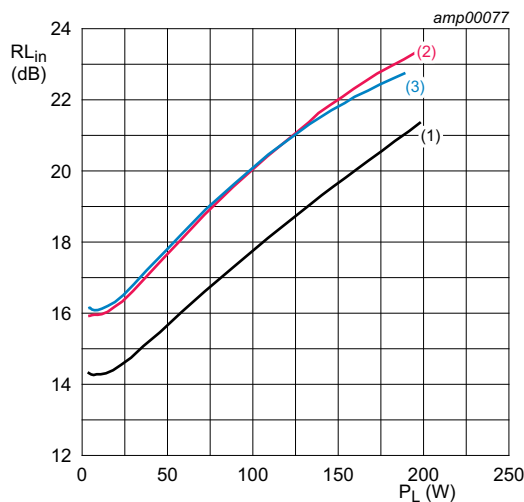
Fig 9. Power gain and drain efficiency as function of output power; typical values



$V_{DS} = 32\text{ V}; I_{Dq} = 810\text{ mA}; V_{GS(amp)peak} = 0.65\text{ V}.$

- (1)  $f = 2117.5\text{ MHz}$
- (2)  $f = 2155\text{ MHz}$
- (3)  $f = 2162.5\text{ MHz}$

Fig 10. Adjacent channel power ratio (5 MHz) as a function of output power; typical values

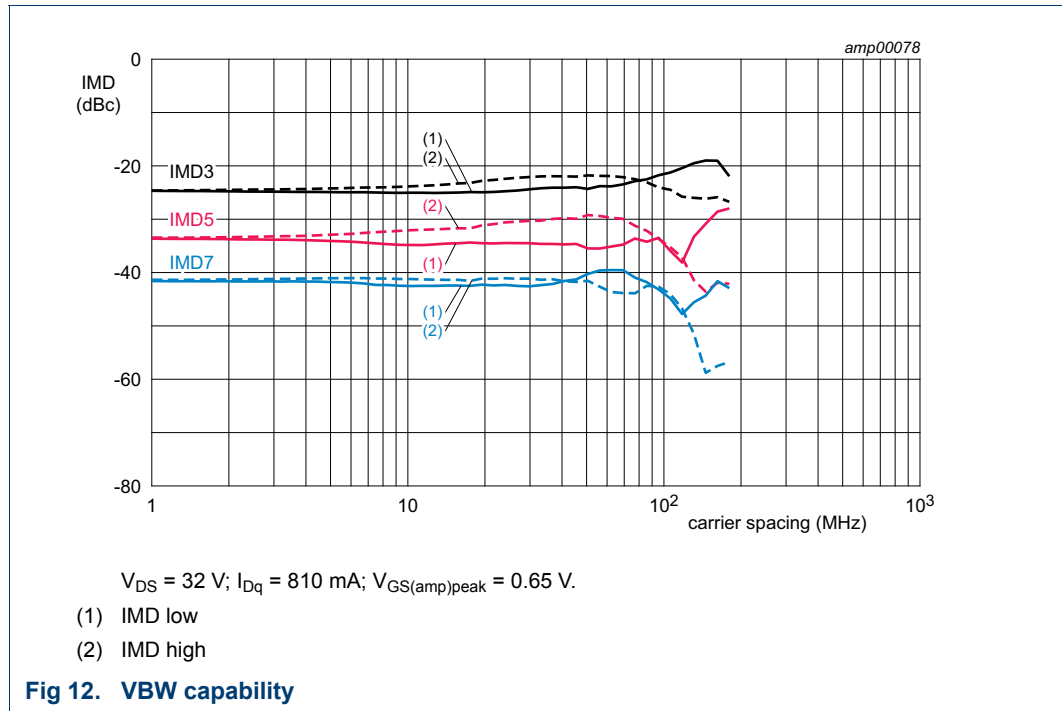


$V_{DS} = 32\text{ V}; I_{Dq} = 810\text{ mA}; V_{GS(amp)peak} = 0.65\text{ V}.$

- (1)  $f = 2117.5\text{ MHz}$
- (2)  $f = 2155\text{ MHz}$
- (3)  $f = 2162.5\text{ MHz}$

Fig 11. Input return loss as a function of output power; typical values

7.5.4 2-Tone VBW



### 8. Package outline

Air cavity plastic earless flanged package; 6 leads

SOT1258-7

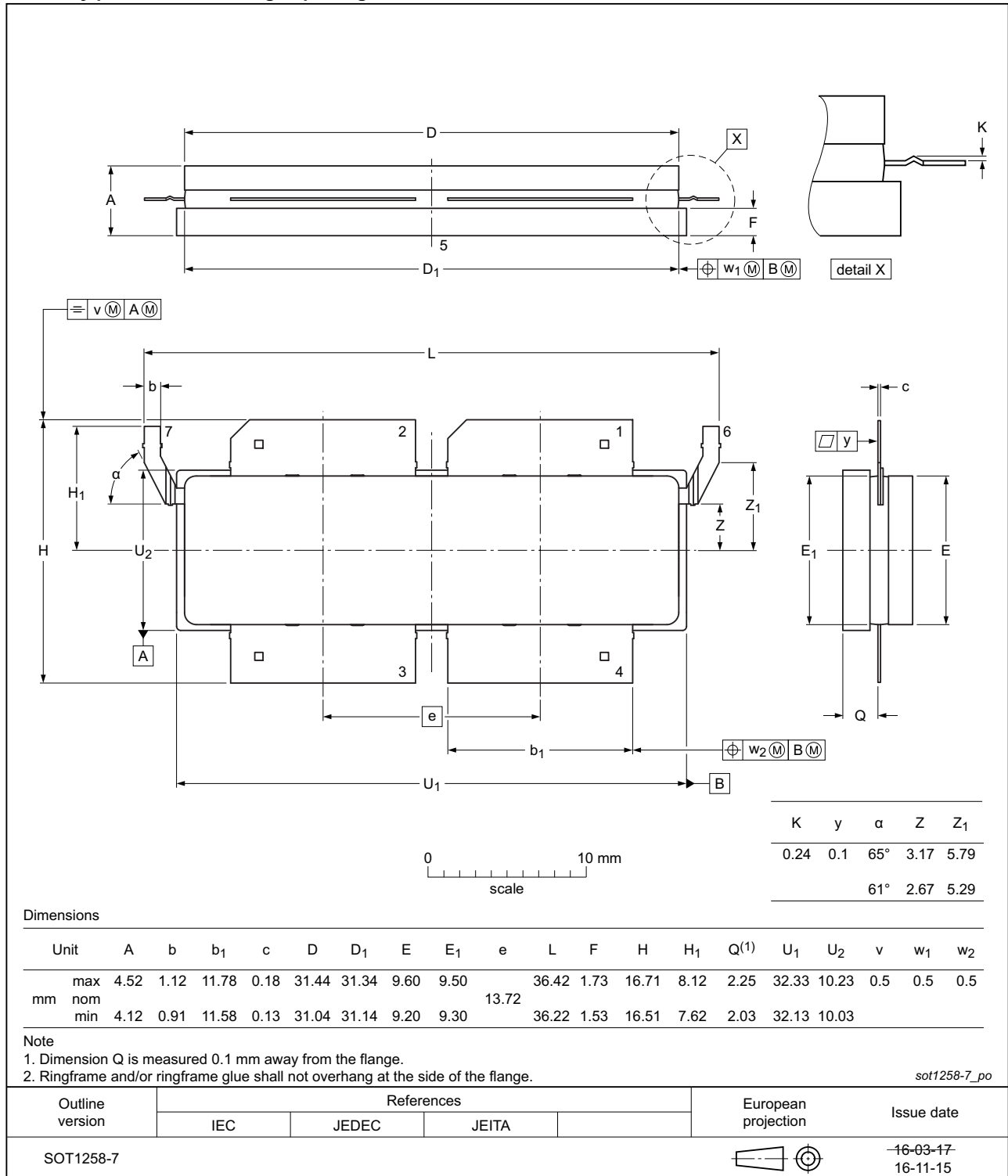



Fig 13. Package outline SOT1258-7

## 9. Handling information

CAUTION	
	<p>This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.</p> <p>Such precautions are described in the <i>ANSI/ESD S20.20</i>, <i>IEC/ST 61340-5</i>, <i>JESD625-A</i> or equivalent standards.</p>

**Table 16. ESD sensitivity**

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A <a href="#">[1]</a>
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 <a href="#">[2]</a>

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

## 10. Abbreviations

**Table 17. Abbreviations**

Acronym	Description
3GPP	3rd Generation Partnership Project
AM	Amplitude Modulation
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
OBO	Output Back Off
PAR	Peak-to-Average Ratio
PM	Phase Modulation
SMD	Surface Mounted Device
VBW	Video BandWidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access



## 11. Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC9G22XS-400AVT v.2	20161202	Product data sheet	-	BLC9G22XS-400AVT v.1
Modifications:	<ul style="list-style-type: none"><li>• <a href="#">Figure 13 on page 12</a>: updated package outline drawing SOT1258-7</li><li>• <a href="#">Section 9 on page 13</a>: updated Handling information</li></ul>			
BLC9G22XS-400AVT v.1	20160513	Product data sheet	-	-

## 12. Legal information

### 12.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

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